### **INTEGRATED CIRCUITS**

### DATA SHEET

### 74HC595; 74HCT595

8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

Product specification Supersedes data of 1998 Jun 04 2003 Jun 25





### 8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

74HC595; 74HCT595

#### **FEATURES**

- · 8-bit serial input
- · 8-bit serial or parallel output
- · Storage register with 3-state outputs
- · Shift register with direct clear
- · 100 MHz (typical) shift out frequency
- ESD protection: HBM EIA/JESD22-A114-A exceeds 2000 V MM EIA/JESD22-A115-A exceeds 200 V.

#### **APPLICATIONS**

- · Serial-to-parallel data conversion
- · Remote control holding register.

#### DESCRIPTION

The 74HC/HCT595 are high-speed Si-gate CMOS devices and are pin compatible with low power Schottky TTL (LSTTL). They are specified in compliance with JEDEC standard no. 7A.

The 74HC/HCT595 is an 8-stage serial shift register with a storage register and 3-state outputs. The shift register and storage register have separate clocks.

Data is shifted on the positive-going transitions of the SH\_CP input. The data in each register is transferred to the storage register on a positive-going transition of the ST\_CP input. If both clocks are connected together, the shift register will always be one clock pulse ahead of the storage register.

The shift register has a serial input (DS) and a serial standard output (Q7') for cascading. It is also provided with asynchronous reset (active LOW) for all 8 shift register stages. The storage register has 8 parallel 3-state bus driver outputs. Data in the storage register appears at the output whenever the output enable input (OE) is LOW.

### **QUICK REFERENCE DATA**

GND = 0 V;  $T_{amb}$  = 25 °C;  $t_r$  =  $t_f$  = 6 ns.

SYMBOL	PARAMETER	CONDITIONS	TYP	UNIT		
STINIBUL	PARAWETER	CONDITIONS	74HC	74HCT	ONII	
t <sub>PHL</sub> /t <sub>PLH</sub>	propagation delay	$C_L = 50 \text{ pF}; V_{CC} = 4.5 \text{ V}$				
	SH_CP to Q7'		19	25	ns	
	SH_CP to Qn		20	24	ns	
	MR to Q7'		100	52	ns	
f <sub>max</sub>	maximum clock frequency SH_CP and ST_CP		100	57	MHz	
Cı	input capacitance		3.5	3.5	pF	
C <sub>PD</sub>	power dissipation capacitance per package	notes 1 and 2	115	130	pF	

### Notes

1.  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in Volts;

N = total load switching outputs;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$  = sum of the outputs.

2. For 74HC595 the condition is  $V_I = GND$  to  $V_{CC}$ .

For 74HCT595 the condition is  $V_I = GND$  to  $V_{CC} - 1.5 V$ .

### 8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

74HC595; 74HCT595

#### **FUNCTION TABLE**

See note 1.

		INPUT			OUT	PUT	FUNCTION
SH_CP	ST_CP	OE	MR	DS	Q7'	Qn	FUNCTION
Х	Х	L	L	Х	L	n.c.	a LOW level on MR only affects the shift registers
Х	1	L	L	Х	L	L	empty shift register loaded into storage register
Х	Х	Н	L	Х	L	Z	shift register clear; parallel outputs in high-impedance OFF-state
<b>↑</b>	Х	L	Н	Н	Q6'	n.c.	logic high level shifted into shift register stage 0; contents of all shift register stages shifted through, e.g. previous state of stage 6 (internal Q6') appears on the serial output (Q7')
Х	1	L	Н	Х	n.c.	Qn'	contents of shift register stages (internal Qn') are transferred to the storage register and parallel output stages
1	1	L,	Н	Х	Q6'	Qn'	contents of shift register shifted through; previous contents of the shift register is transferred to the storage register and the parallel output stages

#### Note

1. H = HIGH voltage level;

L = LOW voltage level;

↑ = LOW-to-HIGH transition;

↓ = HIGH-to-LOW transition;

Z = high-impedance OFF-state;

n.c. = no change;

X = don't care.

#### **ORDERING INFORMATION**

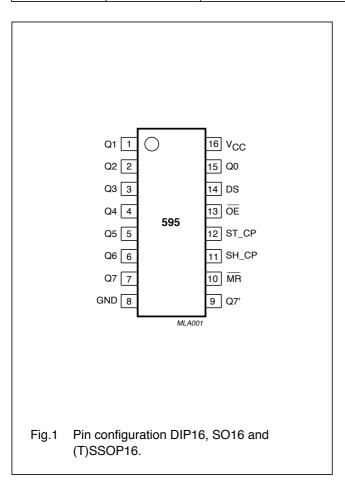
			PACKAGE		
TYPE NUMBER	TEMPERATURE RANGE	PINS	PACKAGE	MATERIAL	CODE
74HC595N	-40 to +125 °C	16	DIP16	plastic	SOT38-4
74HCT595N	-40 to +125 °C	16	DIP16	plastic	SOT38-4
74HC595D	-40 to +125 °C	16	SO16	plastic	SOT109-1
74HCT595D	-40 to +125 °C	16	SO16	plastic	SOT109-1
74HC595DB	-40 to +125 °C	16	SSOP16	plastic	SOT338-1
74HCT595DB	-40 to +125 °C	16	SSOP16	plastic	SOT338-1
74HC595PW	-40 to +125 °C	16	TSSOP16	plastic	SOT403-1
74HCT595PW	-40 to +125 °C	16	TSSOP16	plastic	SOT403-1
74HC595BQ	-40 to +125 °C	16	DHVQFN16	plastic	SOT763-1
74HCT595BQ	–40 to +125 °C	16	DHVQFN16	plastic	SOT763-1

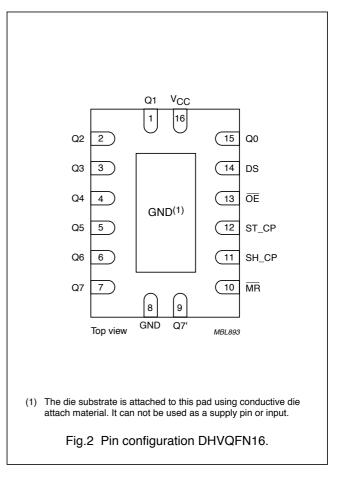
### 8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

74HC595; 74HCT595

### **PINNING**

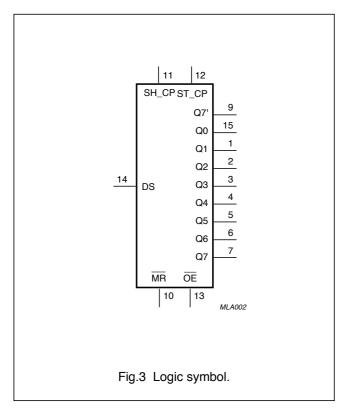
PIN	SYMBOL	DESCRIPTION
1	Q1	parallel data output
2	Q2	parallel data output
3	Q3	parallel data output
4	Q4	parallel data output
5	Q5	parallel data output
6	Q6	parallel data output
7	Q7	parallel data output
8	GND	ground (0 V)
9	Q7'	serial data output
10	MR	master reset (active LOW)
11	SH_CP	shift register clock input
12	ST_CP	storage register clock input
13	ŌĒ	output enable (active LOW)
14	DS	serial data input
15	Q0	parallel data output
16	V <sub>CC</sub>	positive supply voltage

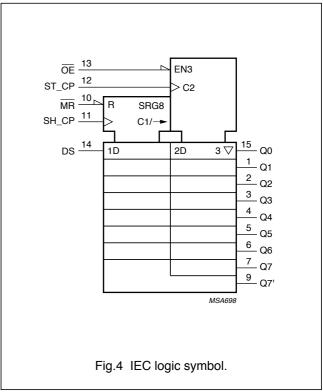


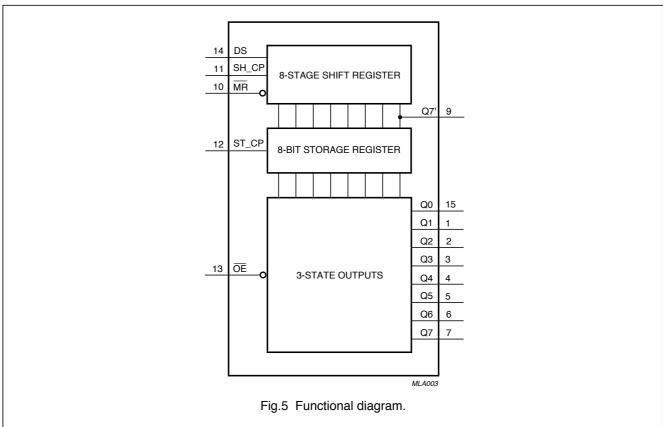


### 8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

### 74HC595; 74HCT595

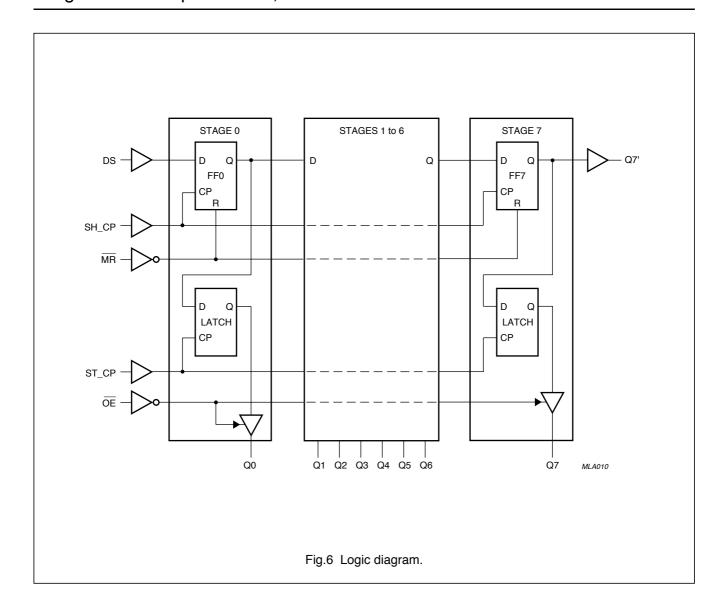






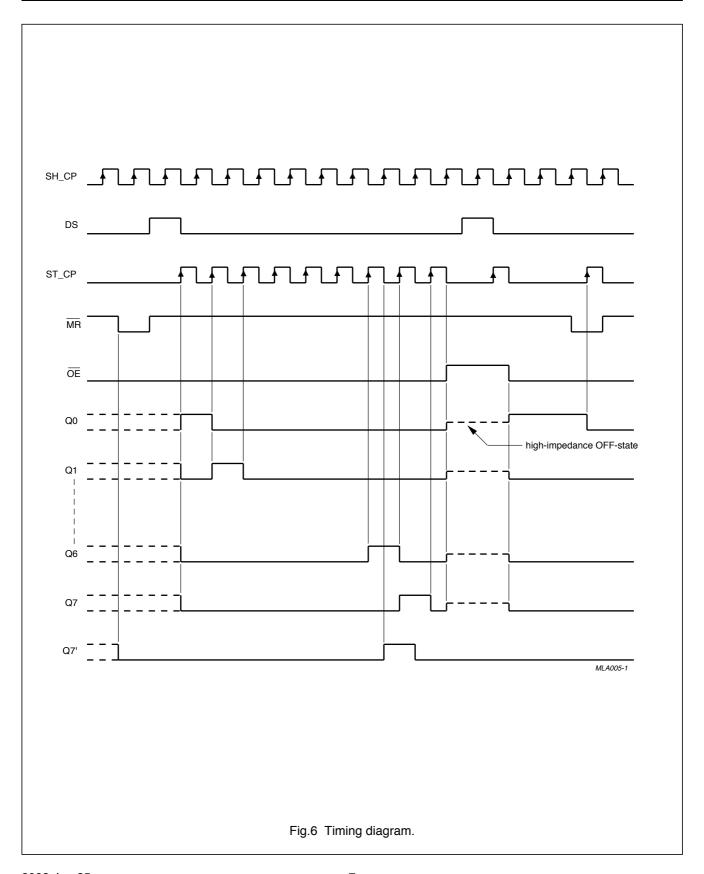
8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

74HC595; 74HCT595



8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

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### 8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

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#### **RECOMMENDED OPERATING CONDITIONS**

SYMBOL	PARAMETER	CONDITIONS	74HC				UNIT		
STWIBUL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
V <sub>CC</sub>	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	٧
VI	input voltage		0	-	V <sub>CC</sub>	0	_	V <sub>CC</sub>	٧
Vo	output voltage		0	_	V <sub>CC</sub>	0	_	V <sub>CC</sub>	٧
T <sub>amb</sub>	ambient temperature		-40	-	+125	-40	_	+125	°C
t <sub>r</sub> , t <sub>f</sub>	input rise and fall time	V <sub>CC</sub> = 2.0 V	_	-	1000	_	_	-	ns
		V <sub>CC</sub> = 4.5 V	_	6.0	500	_	6.0	500	ns
		V <sub>CC</sub> = 6.0 V	_	_	400	_	_	_	ns

#### **LIMITED VALUES**

In accordance with the Absolute Maximum Rating System (IEC 60134); voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CC</sub>	supply voltage		-0.5	+7.0	V
I <sub>IK</sub>	input diode current	$V_{I} < -0.5 \text{ V to } V_{I} > V_{CC} + 0.5 \text{ V}$	_	±20	mA
I <sub>OK</sub>	output diode current	$V_{\rm O}$ < -0.5 V to $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	_	±20	mA
I <sub>O</sub>	output source or sink current	$V_{\rm O} = -0.5 \text{ V to } V_{\rm CC} + 0.5 \text{ V}$			
		Q7' standard output	-	±25	mA
		Qn bus driver outputs	-	±35	mA
I <sub>CC</sub> , I <sub>GND</sub>	V <sub>CC</sub> or GND current		_	±70	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	power dissipation	$T_{amb} = -40 \text{ to } +125 \text{ °C}; \text{ note } 1$	-	500	mW

### Note

1. For DIP16 packages: above 70 °C derate linearly with 12 mW/K.

For SO16 packages: above 70 °C derate linearly with 8 mW/K.

For SSOP16 packages: above 60 °C derate linearly with 5.5 mW/K.

For TSSOP16 packages: above 60 °C derate linearly with 5.5 mW/K.

For DHVQFN16 packages: above 60 °C derate linearly with 4.5 mW/K.

# 8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

74HC595; 74HCT595

### **DC CHARACTERISTICS**

Type 74HC
At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

OVMBOL	DADAMETED	TEST CONDITION	ONS		TVD	MAX.	LINUT
SYMBOL	PARAMETER	OTHER	V <sub>CC</sub> (V)	MIN.	TYP.		UNIT
T <sub>amb</sub> = -40 to	+85 °C; note 1		'	'	1	1	
V <sub>IH</sub>	HIGH-level input		2.0	1.5	1.2	_	٧
	voltage		4.5	3.15	2.4	_	V
			6.0	4.2	3.2	_	V
V <sub>IL</sub>	LOW-level input		2.0	-	0.8	0.5	V
	voltage		4.5	-	2.1	1.35	V
			6.0	_	2.8	1.8	V
V <sub>OH</sub>	HIGH-level output	$V_I = V_{IH}$ or $V_{IL}$					
	voltage	all outputs					
		I <sub>O</sub> = -20 μA	2.0	1.9	2.0	_	V
			4.5	4.4	4.5	_	V
			6.0	5.9	6.0	_	V
		Q7' standard output					
		$I_{O} = -4.0 \text{ mA}$	4.5	3.84	4.32	_	V
		$I_{O} = -5.2 \text{ mA}$	6.0	5.34	5.81	_	V
		Qn bus driver outputs					
		$I_{O} = -6.0 \text{ mA}$	4.5	3.84	4.32	_	V
		$I_{O} = -7.8 \text{ mA}$	6.0	5.34	5.81	_	V
V <sub>OL</sub>	LOW-level output	$V_I = V_{IH}$ or $V_{IL}$					
	voltage	all outputs					
		I <sub>O</sub> = 20 μA	2.0	-	0	0.1	V
			4.5	-	0	0.1	V
			6.0	_	0	0.1	V
		Q7' standard output					
		$I_{O} = 4.0 \text{ mA}$	4.5	-	0.15	0.33	V
		$I_{O} = 5.2 \text{ mA}$	6.0	_	0.16	0.33	V
		Qn bus driver outputs					
		$I_{O} = 6.0 \text{ mA}$	4.5	_	0.16	0.33	V
		I <sub>O</sub> = 7.8 mA	6.0	_	0.16	0.33	V
l <sub>LI</sub>	input leakage current	$V_I = V_{CC}$ or GND	6.0	_	-	±1.0	μΑ
l <sub>oz</sub>	3-state output OFF-state current	$V_I = V_{IH} \text{ or } V_{IL};$ $V_O = V_{CC} \text{ or GND}$	6.0	_	_	±5.0	μΑ
I <sub>CC</sub>	quiescent supply current	$V_I = V_{CC}$ or GND; $I_O = 0$	6.0	-	-	80	μΑ

# 8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

74HC595; 74HCT595

CVMDOL	DADAMETED	TEST CONDITION	ONS	NAIN!	TVD	NA A W	
SYMBOL	PARAMETER	OTHER	V <sub>CC</sub> (V)	MIN.	TYP.	MAX.	UNIT
T <sub>amb</sub> = -40 to	o +125 °C		'	•			'
V <sub>IH</sub>	HIGH-level input		2.0	1.5	_	_	V
	voltage		4.5	3.15	_	_	V
			6.0	4.2	_	_	V
V <sub>IL</sub>	LOW-level input		2.0	_	_	0.5	V
	voltage		4.5	_	_	1.35	V
			6.0	_	_	1.8	V
V <sub>OH</sub>	HIGH-level output	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>					
	voltage	all outputs					
		$I_{O} = -20 \mu A$	2.0	1.9	_	_	V
			4.5	4.4	_	_	V
			6.0	5.9	_	_	V
		Q7' standard output					
		$I_{O} = -4.0 \text{ mA}$	4.5	3.7	_	_	V
		$I_{O} = -5.2 \text{ mA}$	6.0	5.2	_	_	V
		Qn bus driver outputs					
		$I_{O} = -6.0 \text{ mA}$	4.5	3.7	_	_	V
		$I_{O} = -7.8 \text{ mA}$	6.0	5.2	_	_	V
V <sub>OL</sub>	LOW-level output	$V_I = V_{IH}$ or $V_{IL}$					
	voltage	all outputs					
		$I_{O} = 20 \mu A$	4.5	_	_	0.1	V
		Q7' standard output					
		$I_{O} = 4.0 \text{ mA}$	4.5	_	_	0.4	V
		Qn bus driver outputs					
		$I_{O} = 6.0 \text{ mA}$	4.5	_	_	0.4	V
l <sub>Ll</sub>	input leakage current	$V_I = V_{CC}$ or GND	5.5	-	_	±1.0	μΑ
l <sub>OZ</sub>	3-state output OFF-state current	$V_I = V_{IH} \text{ or } V_{IL};$ $V_O = V_{CC} \text{ or GND}$	5.5	_	-	±10.0	μΑ
lcc	quiescent supply current	$V_I = V_{CC}$ or GND; $I_O = 0$	5.5	_	-	160	μΑ

### Note

1. All typical values are measured at  $T_{amb}$  = 25 °C.

### 8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

74HC595; 74HCT595

Type 74HCT At recommended operating conditions; voltages are referenced to GND (ground = 0 V);  $t_r = t_f = 6$  ns;  $C_L = 50$  pF.

OVMBOL	DADAMETER	TEST CONDITI	ONS		TVD	NA AV	LINUT
SYMBOL	PARAMETER	OTHER	V <sub>CC</sub> (V)	MIN.	TYP.	MAX.	UNIT
T <sub>amb</sub> = -40 to	+85 °C; note 1	•					
V <sub>IH</sub>	HIGH-level input voltage		4.5 to 5.5	2.0	1.6		V
V <sub>IL</sub>	LOW-level input voltage		4.5 to 5.5	-	1.2	0.8	V
V <sub>OH</sub>	HIGH-level output	$V_I = V_{IH}$ or $V_{IL}$					
	voltage	all outputs					
		$I_{O} = -20 \mu A$	4.5	4.4	4.5	_	V
		Q7' standard output					
		$I_{O} = -4.0 \text{ mA}$	4.5	3.84	4.32	_	V
		Qn bus driver outputs					
		$I_{O} = -6.0 \text{ mA}$	4.5	3.7	4.32	_	V
V <sub>OL</sub>	LOW-level output	$V_I = V_{IH}$ or $V_{IL}$					
	voltage	all outputs					
		I <sub>O</sub> = 20 μA	4.5	_	0	0.33	V
		Q7' standard output					
		$I_{O} = 4.0 \text{ mA}$	4.5	_	0.15	0.33	V
		Qn bus driver outputs					
		$I_{O} = 6.0 \text{ mA}$	4.5	_	0.16	0.33	V
ILI	input leakage current	$V_I = V_{CC}$ or GND	5.5	_	_	±1.0	μΑ
I <sub>OZ</sub>	3-state output OFF-state current	$V_I = V_{IH} \text{ or } V_{IL};$ $V_O = V_{CC} \text{ or GND}$	5.5	_	_	±5.0	μΑ
I <sub>CC</sub>	quiescent supply current	$V_I = V_{CC}$ or GND; $I_O = 0$	5.5	_	-	80	μΑ
Δl <sub>CC</sub>	additional supply current per input	$V_I = V_{CC} - 2.1 \text{ V};$ $I_O = 0; \text{ note } 2$	4.5 to 5.5	_	100	450	μΑ

### 8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

74HC595; 74HCT595

CVMDOL	DADAMETER	TEST CONDITI	ONS	BAIN	TVD	MAY	
SYMBOL	PARAMETER	OTHER	V <sub>CC</sub> (V)	MIN.	TYP.	MAX.	UNIT
T <sub>amb</sub> = -40 to	o +125 °C					•	
V <sub>IH</sub>	HIGH-level input voltage		4.5 to 5.5	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage		4.5 to 5.5	-	-	0.8	V
V <sub>OH</sub>	HIGH-level output	$V_I = V_{IH}$ or $V_{IL}$					
	voltage	all outputs					
		$I_{O} = -20 \mu A$	4.5	4.4	_	_	V
		Q7' standard output					
		$I_{O} = -4.0 \text{ mA}$	4.5	3.7	_	_	V
		Qn bus driver outputs					
		$I_{O} = -6.0 \text{ mA}$	4.5	3.7	_	_	V
V <sub>OL</sub>	LOW-level output	$V_I = V_{IH}$ or $V_{IL}$					
	voltage	all outputs					
		I <sub>O</sub> = 20 μA	4.5	_	_	0.1	V
		Q7' standard output					
		$I_{O} = 4.0 \text{ mA}$	4.5	_	_	0.4	V
		Qn bus driver outputs					
		$I_{O} = 6.0 \text{ mA}$	4.5	_	_	0.4	V
I <sub>LI</sub>	input leakage current	$V_I = V_{CC}$ or GND	5.5	_	_	±1.0	μΑ
I <sub>OZ</sub>	3-state output OFF-state current	$V_I = V_{IH}$ or $V_{IL}$ ; $V_O = V_{CC}$ or GND	5.5	_	-	±10.0	μА
I <sub>CC</sub>	quiescent supply current	$V_I = V_{CC}$ or GND; $I_O = 0$	5.5	_	-	160	μΑ
Δl <sub>CC</sub>	additional supply current per input	$V_{I} = V_{CC} - 2.1 \text{ V};$ $I_{O} = 0; \text{ note } 2$	4.5 to 5.5	_	-	490	μΑ

#### **Notes**

- 1. All typical values are measured at  $T_{amb} = 25$  °C.
- 2. The value of additional quiescent supply current ( $\Delta I_{CC}$ ) for a unit load of 1 is given here. To determine  $\Delta I_{CC}$  per input, multiply this value by the unit load coefficient per input pin:
  - a. pin DS: 0.25
  - b. pins  $\overline{\text{MR}}$ , SH\_CP, ST\_CP and  $\overline{\text{OE}}$ : 1.50.

# 8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

74HC595; 74HCT595

### **AC CHARACTERISTICS**

### Family 74HC

 $GND = 0 \ V; \, t_r = t_f = 6 \ ns; \, C_L = 50 \ pF. \label{eq:continuous}$ 

0.41501		TEST CONDIT	TIONS			MAY	
SYMBOL	PARAMETER	WAVEFORMS	V <sub>CC</sub> (V)	MIN.	TYP.	MAX.	UNIT
T <sub>amb</sub> = 25 °C			•		•		•
t <sub>PHL</sub> /t <sub>PLH</sub>	propagation delay	see Fig.7	2.0	_	52	160	ns
	SH_CP to Q7'		4.5	_	19	32	ns
			6.0	_	15	27	ns
	propagation delay	see Fig.8	2.0	_	55	175	ns
	ST_CP to Qn		4.5	_	20	35	ns
			6.0	_	16	30	ns
t <sub>PHL</sub>	propagation delay	see Fig.10	2.0	_	47	175	ns
	MR to Q7'		4.5	_	17	35	ns
			6.0	_	14	30	ns
t <sub>PZH</sub> /t <sub>PZL</sub>	3-state output enable time	see Fig.11	2.0	_	47	150	ns
	OE to Qn		4.5	_	17	30	ns
			6.0	_	14	26	ns
t <sub>PHZ</sub> /t <sub>PLZ</sub>	3-state output disable time OE to Qn	see Fig.11	2.0	_	41	150	ns
			4.5	_	15	30	ns
			6.0	_	12	26	ns
t <sub>W</sub>	shift clock pulse width	see Fig.7	2.0	75	17	_	ns
	HIGH or LOW		4.5	15	6	_	ns
			6.0	13	5	_	ns
	storage clock pulse width HIGH or LOW	see Fig.8	2.0	75	11	_	ns
			4.5	15	4	_	ns
			6.0	13	3	_	ns
	master reset pulse width	see Fig.10	2.0	75	17	_	ns
	LOW		4.5	15	6.0	_	ns
			6.0	13	5.0	_	ns
t <sub>su</sub>	set-up time DS to SH_CP	see Fig.9	2.0	50	11	_	ns
			4.5	10	4.0	_	ns
			6.0	9.0	3.0	_	ns
	set-up time	see Fig.8	2.0	75	22	_	ns
	SH_CP to ST_CP		4.5	15	8	_	ns
			6.0	13	7	_	ns
t <sub>h</sub>	hold time DS to SH_CP	see Fig.9	2.0	+3	-6	_	ns
		_	4.5	+3	-2	_	ns
			6.0	+3	-2	_	ns

# 8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

74HC595; 74HCT595

0)////	DADAMETED	TEST CONDIT	TIONS		T)(D	BAAV	
SYMBOL	PARAMETER	WAVEFORMS	V <sub>CC</sub> (V)	MIN.	TYP.	MAX.	UNIT
t <sub>rem</sub>	removal time MR to SH_CP	see Fig.10	2.0	+50	-19	1-	ns
			4.5	+10	-7	-	ns
			6.0	+9	-6	_	ns
f <sub>max</sub>	maximum clock	see Figs 7 and 8	2.0	9	30	_	MHz
	pulse frequency		4.5	30	91	_	MHz
	SH_CP or ST_CP		6.0	35	108	-	MHz
T <sub>amb</sub> = -40 t	o +85 °C				•	•	•
t <sub>PHL</sub> /t <sub>PLH</sub>	propagation delay	see Fig.7	2.0	l_	T =	200	ns
	SH_CP to Q7'	J	4.5	-	1-	40	ns
			6.0	-	1-	34	ns
	propagation delay	see Fig.8	2.0	_	1_	220	ns
	ST_CP to An	J	4.5	_	1-	44	ns
			6.0	_	_	37	ns
t <sub>PHL</sub>	propagation delay MR to Q7'	see Fig.10	2.0	_	1-	220	ns
		, o	4.5	_	_	44	ns
			6.0	_	_	37	ns
t <sub>PZH</sub> /t <sub>PZL</sub>	3-state output enable time	see Fig.11	2.0	_	_	190	ns
	OE to Qn	, o	4.5	_	_	38	ns
			6.0	_	<u> </u>	33	ns
t <sub>PHZ</sub> /t <sub>PLZ</sub>	3-state output disable time OE to Qn	see Fig.11	2.0	_	_	190	ns
			4.5	_	_	38	ns
			6.0	_	-	33	ns
t <sub>W</sub>	shift clock pulse width	see Fig.7	2.0	95	_	-	ns
	HIGH or LOW	-	4.5	19	_	-	ns
			6.0	16	-	-	ns
	storage clock pulse width	see Fig.8	2.0	95	-	-	ns
	HIGH or LOW	-	4.5	19	-	-	ns
			6.0	16	-	-	ns
	master reset pulse width	see Fig.10	2.0	95	-	-	ns
	LOW	-	4.5	19	-	1-	ns
			6.0	16	-	-	ns
t <sub>su</sub>	set-up time DS to SH_CP	see Fig.9	2.0	65	-	-	ns
			4.5	13	-	-	ns
			6.0	11	-	-	ns
	set-up time	see Fig.8	2.0	95	-	-	ns
	SH_CP to ST_CP		4.5	19	-	1-	ns
			6.0	16	_	_	ns

# 8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

74HC595; 74HCT595

OVMDOL	DADAMETED	TEST CONDIT	TIONS		T\/D	B. A. W	
SYMBOL	PARAMETER	WAVEFORMS	V <sub>CC</sub> (V)	MIN.	TYP.	MAX.	UNIT
t <sub>h</sub>	hold time DS to SH_CP	see Fig.9	2.0	3	_	-	ns
			4.5	3	_	_	ns
			6.0	3	_	_	ns
t <sub>rem</sub>	removal time MR to SH_CP	see Fig.10	2.0	65	_	_	ns
			4.5	13	_	_	ns
			6.0	11	_	_	ns
f <sub>max</sub>	maximum clock	see Figs 7 and 8	2.0	4.8	_	_	MHz
	pulse frequency		4.5	24	_	_	MHz
	SH_CP or ST_CP		6.0	28	_	_	MHz
T <sub>amb</sub> = -40 1	to +125 °C					•	
t <sub>PHL</sub> /t <sub>PLH</sub>	propagation delay	see Fig.7	2.0	_	_	240	ns
	SH_CP to Q7'		4.5	_	_	48	ns
			6.0	_	_	41	ns
	propagation delay	see Fig.8	2.0	_	_	265	ns
	ST_CP to Qn		4.5	_	_	53	ns
			6.0	-	_	45	ns
t <sub>PHL</sub>	propagation delay	see Fig.10	2.0	_	_	265	ns
	MR to Q7'		4.5	-	_	53	ns
			6.0	-	_	45	ns
t <sub>PZH</sub> /t <sub>PZL</sub>	3-state output enable time	see Fig.11	2.0	_	_	225	ns
	OE to Qn		4.5	_	_	45	ns
			6.0	_	_	38	ns
t <sub>PHZ</sub> /t <sub>PLZ</sub>	3-state output disable time	see Fig.11	2.0	_	_	225	ns
	OE to Qn		4.5	_	_	45	ns
			6.0	_	_	38	ns
t <sub>W</sub>	shift clock pulse width	see Fig.7	2.0	110	_	_	ns
	HIGH or LOW		4.5	22	_	_	ns
			6.0	19	_	_	ns
	storage clock pulse width	see Fig.8	2.0	110	_	_	ns
	HIGH or LOW		4.5	22	_	_	ns
			6.0	19	_	-	ns
	master reset pulse width	see Fig.10	2.0	110	1_	_	ns
	LOW		4.5	22	_	_	ns
			6.0	19	<del> </del>	_	ns

# 8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

74HC595; 74HCT595

CVMDOL	DADAMETED	TEST CONDIT	IONS	DAIN!	TVD	MAY	LINUT
SYMBOL	PARAMETER	WAVEFORMS	V <sub>CC</sub> (V)	MIN.	TYP.	MAX.	UNIT
t <sub>su</sub>	set-up time DS to SH_CP	see Fig.9	2.0	75	_	_	ns
			4.5	15	_	_	ns
			6.0	13	_	_	ns
	set-up time	see Fig.8	2.0	110	_	_	ns
	SH_CP to ST_CP		4.5	22	_	_	ns
			6.0	19	_	_	ns
t <sub>h</sub>	hold time DS to SH_CP	see Fig.9	2.0	3	_	_	ns
			4.5	3	_	_	ns
			6.0	3	_	_	ns
t <sub>rem</sub>	removal time MR to SH_CP	see Fig.10	2.0	75	_	_	ns
			4.5	15	_	_	ns
			6.0	13	_	_	ns
f <sub>max</sub>	maximum clock	see Figs 7 and 8	2.0	4	_	_	MHz
	pulse frequency SH_CP or ST_CP		4.5	20	_	_	MHz
			6.0	24	_	_	MHz

### 8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

74HC595; 74HCT595

Family 74HCT

 $\label{eq:gnd} \text{GND} = 0 \text{ V; } t_r = t_\text{f} = 6 \text{ ns; } C_\text{L} = 50 \text{ pF.}$ 

CVMDOL	DADAMETED	TEST CONDIT	TIONS	NAIN!	TVD	MAY	
SYMBOL	PARAMETER	WAVEFORMS	V <sub>CC</sub> (V)	- MIN.	TYP.	MAX.	UNIT
T <sub>amb</sub> = 25 °C	;		!	•		-!-	
t <sub>PHL</sub> /t <sub>PLH</sub>	propagation delay SH_CP to Q7'	see Fig.7	4.5	-	25	42	ns
	propagation delay ST_CP to Qn	see Fig.8	4.5	_	24	40	ns
t <sub>PHL</sub>	propagation delay MR to Q7'	see Fig.10	4.5	_	23	40	ns
t <sub>PZH</sub> /t <sub>PZL</sub>	3-state output enable time <del>OE</del> to Qn	see Fig.11	4.5	_	21	35	ns
t <sub>PHZ</sub> /t <sub>PLZ</sub>	3-state output disable time <del>OE</del> to Qn	see Fig.11	4.5	_	18	30	ns
t <sub>W</sub>	shift clock pulse width HIGH or LOW	see Fig.7	4.5	16	6	_	ns
	storage clock pulse width HIGH or LOW	see Fig.8	4.5	16	5	-	ns
	master reset pulse width LOW	see Fig.10	4.5	20	8	-	ns
t <sub>su</sub>	set-up time DS to SH_CP	see Fig.9	4.5	16	5	_	ns
	set-up time SH_CP to ST_CP	see Fig.8	4.5	16	8	_	ns
t <sub>h</sub>	hold time DS to SH_CP	see Fig.9	4.5	+3	-2	_	ns
t <sub>rem</sub>	removal time MR to SH_CP	see Fig.10	4.5	+10	-7	_	ns
f <sub>max</sub>	maximum clock pulse frequency SH_CP or ST_CP	see Figs 7 and 8	4.5	30	52	_	MHz
$T_{amb} = -40 \text{ to}$	o +85 °C						
t <sub>PHL</sub> /t <sub>PLH</sub>	propagation delay SH_CP to Q7'	see Fig.7	4.5	_	-	53	ns
	propagation delay ST_CP to Qn	see Fig.8	4.5	_	-	50	ns
t <sub>PHL</sub>	propagation delay MR to Q7'	see Fig.10	4.5	_	_	50	ns
t <sub>PZH</sub> /t <sub>PZL</sub>	3-state output enable time <del>OE</del> to Qn	see Fig.11	4.5	_	-	44	ns
t <sub>PHZ</sub> /t <sub>PLZ</sub>	3-state output disable time <del>OE</del> to Qn	see Fig.11	4.5	_	-	38	ns

# 8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

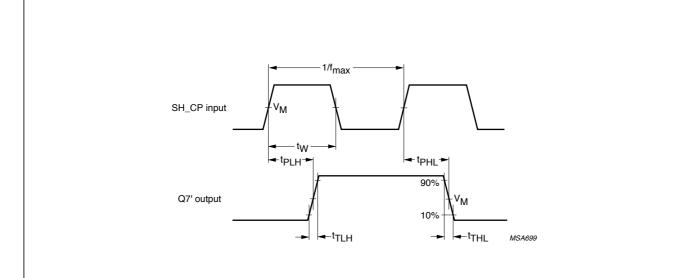
74HC595; 74HCT595

OVMBOL	DADAMETED	TEST CONDI	TIONS		TVD	NAAW.	
SYMBOL	PARAMETER	WAVEFORMS	V <sub>CC</sub> (V)	MIN.	TYP.	MAX.	UNIT
t <sub>W</sub>	shift clock pulse width HIGH or LOW	see Fig.7	4.5	20	-	-	ns
	storage clock pulse width HIGH or LOW	see Fig.8	4.5	20	_	_	ns
	master reset pulse width LOW	see Fig.10	4.5	25	-	_	ns
t <sub>su</sub>	set-up time DS to SH_CP	see Fig.9	4.5	20	_	_	ns
	set-up time SH_CP to ST_CP	see Fig.8	4.5	20	-	_	ns
t <sub>h</sub>	hold time DS to SH_CP	see Fig.9	4.5	3	_	_	ns
t <sub>rem</sub>	removal time MR to SH_CP	see Fig.10	4.5	13	-	_	ns
f <sub>max</sub>	maximum clock pulse frequency SH_CP or ST_CP	see Figs 7 and 8	4.5	24	-	-	MHz
T <sub>amb</sub> = -40 to	o +125 °C		•	•	•	-	•
t <sub>PHL</sub> /t <sub>PLH</sub>	propagation delay SH_CP to Q7'	see Fig.7	4.5	_	-	63	ns
	propagation delay ST_CP to Qn	see Fig.8	4.5	_	-	60	ns
t <sub>PHL</sub>	propagation delay MR to Q7'	see Fig.10	4.5	_	-	60	ns
t <sub>PZH</sub> /t <sub>PZL</sub>	3-state output enable time <del>OE</del> to Qn	see Fig.11	4.5	-	-	53	ns
t <sub>PHZ</sub> /t <sub>PLZ</sub>	3-state output disable time <del>OE</del> to Qn	see Fig.11	4.5	_	-	45	ns
t <sub>W</sub>	shift clock pulse width HIGH or LOW	see Fig.7	4.5	24	_	_	ns
	storage clock pulse width HIGH or LOW	see Fig.8	4.5	24	_	_	ns
	master reset pulse width LOW	see Fig.10	4.5	30	_	_	ns
t <sub>su</sub>	set-up time DS to SH_CP	see Fig.9	4.5	24	_	_	ns
	set-up time SH_CP to ST_CP	see Fig.8	4.5	24	_	_	ns
t <sub>h</sub>	hold time DS to SH_CP	see Fig.9	4.5	3	_	_	ns
t <sub>rem</sub>	removal time MR to SH_CP	see Fig.10	4.5	15	-	_	ns
f <sub>max</sub>	maximum clock pulse frequency SH_CP or ST_CP	see Figs 7 and 8	4.5	20	_	_	MHz

### 8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

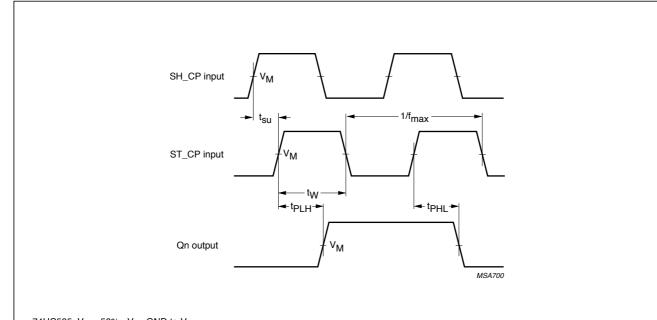
74HC595; 74HCT595

#### **AC WAVEFORMS**



74HC595:  $V_M = 50\%$ ;  $V_I = GND$  to  $V_{CC}$ . 74HCT595:  $V_M = 1.3$  V;  $V_I = GND$  to 3 V.

Fig.7 Waveforms showing the clock (SH\_CP) to output (Q7') propagation delays, the shift clock pulse width and maximum shift clock frequency.

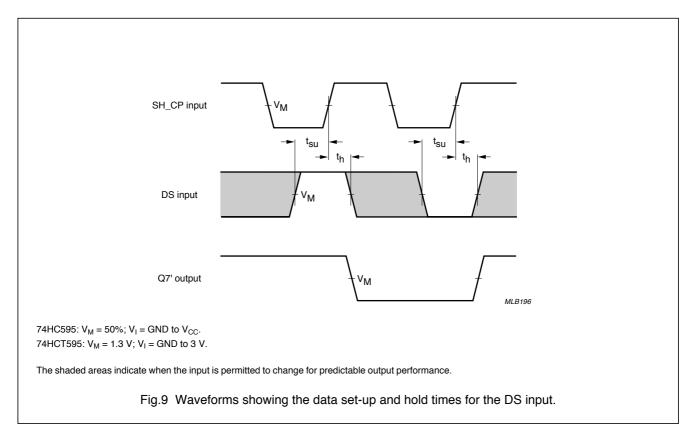


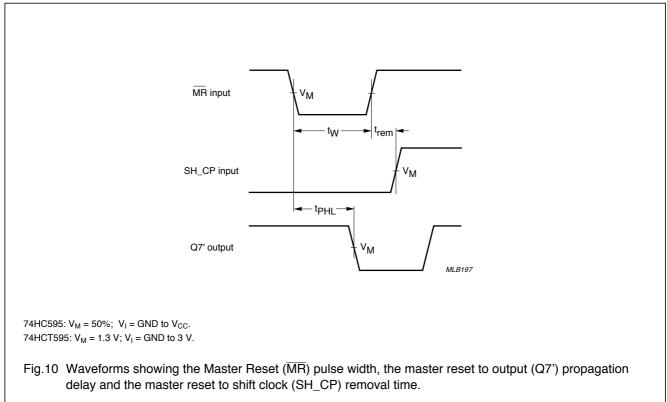
74HC595:  $V_M$  = 50%;  $V_I$  = GND to  $V_{CC}$ . 74HCT595:  $V_M$  = 1.3 V;  $V_I$  = GND to 3 V.

Fig.8 Waveforms showing the storage clock (ST\_CP) to output (Qn) propagation delays, the storage clock pulse width and the shift clock to storage clock set-up time.

### 8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

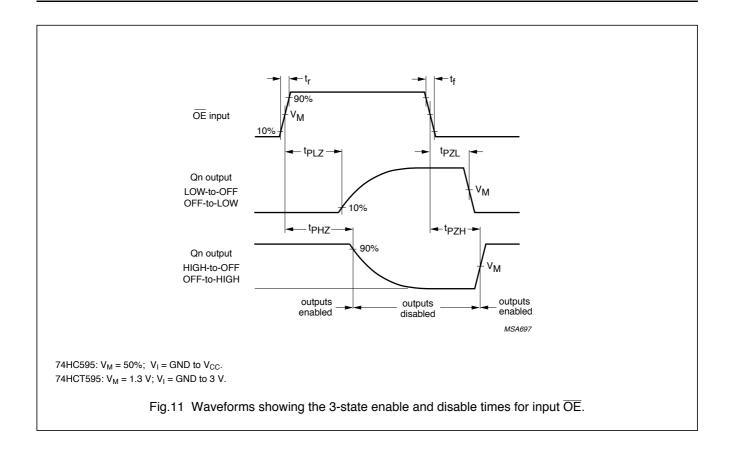
74HC595; 74HCT595

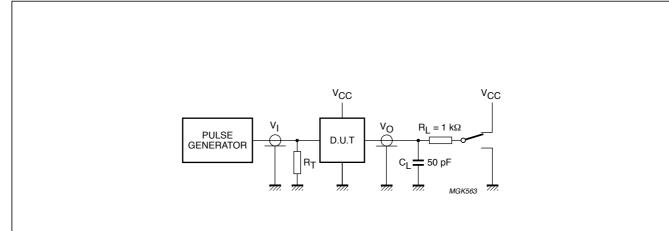




### 8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

74HC595; 74HCT595





TEST	SWITCH
t <sub>PLH</sub> /t <sub>PHL</sub>	open
t <sub>PLZ</sub> /t <sub>PZL</sub>	V <sub>CC</sub>
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND

Definitions for test circuit:

 $R_L$  = Load resistor.

 $C_L$  = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance should be equal to the output impedance  $Z_0$  of the pulse generator.

Fig.12 Test circuit for 3-state outputs.

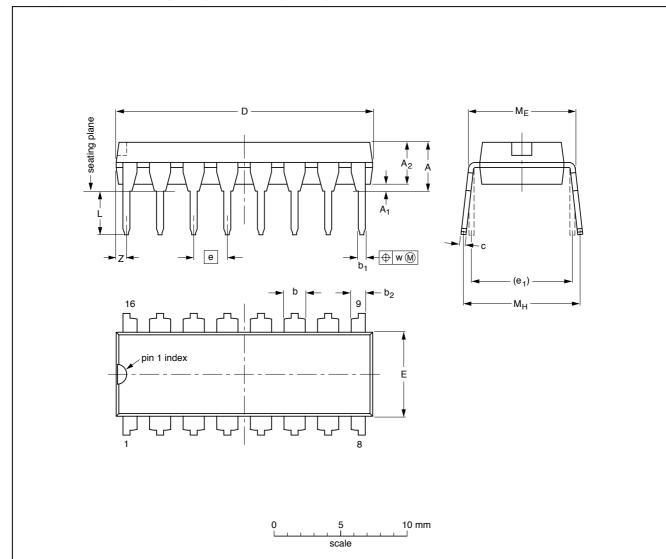
### 8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

74HC595; 74HCT595

### **PACKAGE OUTLINES**

DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4



### DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A <sub>1</sub> min.	A <sub>2</sub> max.	b	b <sub>1</sub>	b <sub>2</sub>	O	D <sup>(1)</sup>	E <sup>(1)</sup>	е	e <sub>1</sub>	L	ME	Мн	w	Z <sup>(1)</sup> max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	1.25 0.85	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	0.76
inches	0.17	0.02	0.13	0.068 0.051	0.021 0.015	0.049 0.033	0.014 0.009	0.77 0.73	0.26 0.24	0.1	0.3	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.03

#### Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

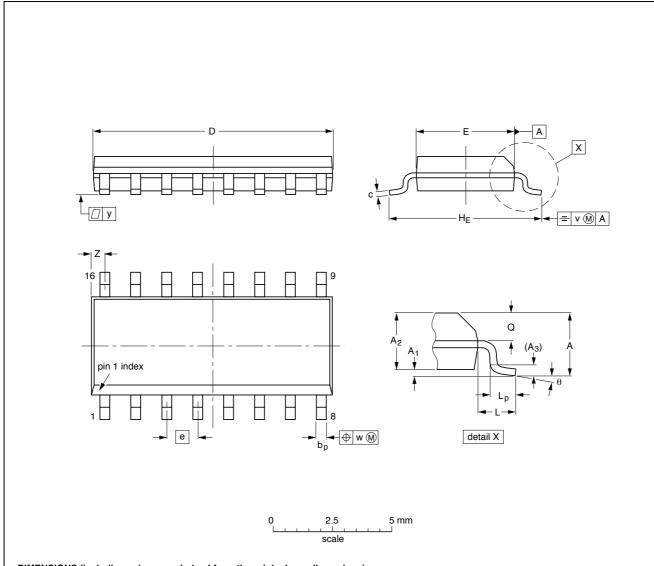
OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT38-4					<del>95-01-14</del> 03-02-13

### 8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

74HC595; 74HCT595

### SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



### DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	b <sub>p</sub>	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075	0.39 0.38	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.020	0.01	0.01	0.004	0.028 0.012	0°

#### Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

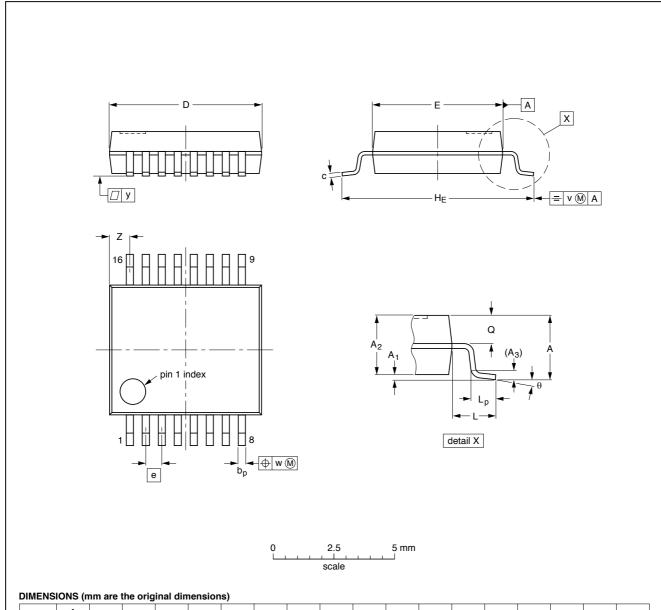
OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT109-1	076E07	MS-012			<del>99-12-27</del> 03-02-19

### 8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

74HC595; 74HCT595

### SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1



•	·	.0.10 (	a.o	09	a. a	.0	٠,												
	UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
	mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.00 0.55	8° 0°

#### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

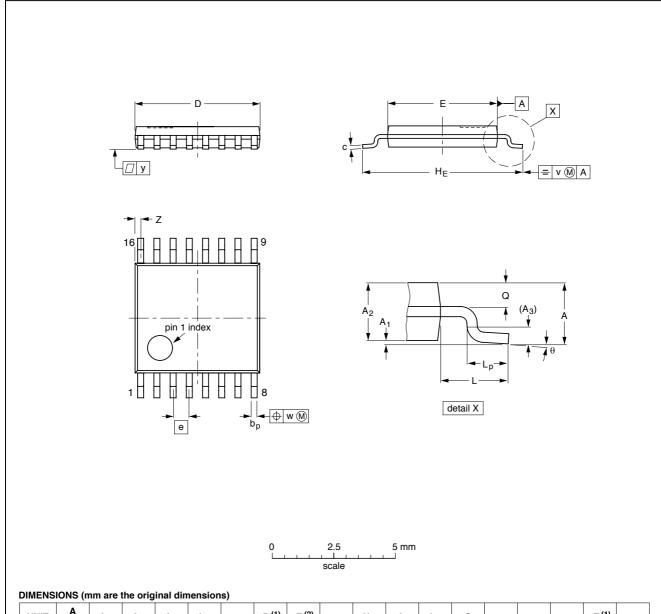
OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT338-1		MO-150			<del>99-12-27</del> 03-02-19

### 8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

74HC595; 74HCT595

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



						-,												
UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(2)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

#### Notes

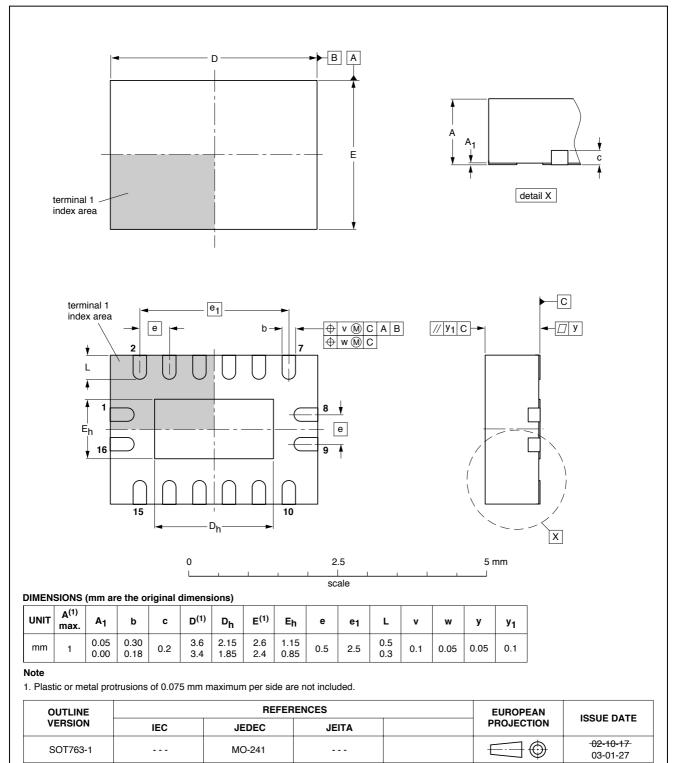
- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN	ISSUE DATE
	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT403-1		MO-153				<del>99-12-27</del> 03-02-18

8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

74HC595; 74HCT595

DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm SOT763-1



### 8-bit serial-in, serial or parallel-out shift register with output latches; 3-state

74HC595; 74HCT595

#### **DATA SHEET STATUS**

LEVEL	DATA SHEET STATUS <sup>(1)</sup>	PRODUCT STATUS(2)(3)	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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